NSN 5961-01-253-2817

Fiig: A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-253-2817 **Inclosure Material:** Metal **Overall Length:** 7.542 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-94 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak off-state voltage and 300.0 repetitive peak reverse voltage and 380.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms horsepower metric and 1800.00 amperes peak forward surge current absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector not applicable **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpnp **Thread Series Designator: Terminal Type And Quantity:** 3 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No